

Supplementary Information

Tellurium Recovery from the Thermoelectric Materials Bismuth Telluride and Antimony Telluride by Chemical Vapour Transport

Julian Burkhardt,^a Lucas H. Bemfert,^a Eliane L. Mitura,^a Moritz Maxeiner,^a Ruben Maile,^a Alexander E. Sedykh^a and Klaus Müller-Buschbaum^{*ab}

^a. Institute of Inorganic and Analytical Chemistry, Justus-Liebig-University Giessen, Heinrich-Buff-Ring 17, 35392 Giessen, Germany.

E-Mail: kmbac@uni-giessen.de

Web: <https://www.uni-giessen.de/de/fbz/fb08/Inst/iaac/mueller-buschbaum>

^b. Center for Materials Research (LAMA), Justus-Liebig-University Giessen, Heinrich-Buff-Ring 16, 35392 Giessen, Germany.

Contents

Chemical vapour transport (CVT) in closed experimental setups	2
Differential scanning calorimetry (DSC)	5
Powder X-ray diffractometry (PXRD)	10
Raman spectroscopy	15
Energy dispersive X-ray analysis (EDX)	16
References	19

Chemical vapour transport (CVT) in closed experimental setups

Table S1: Parameters and results of the closed Bi₂Te₃/S temperature gradient investigations.

System	T ₁ / °C	T ₂ / °C	Te:S molar ratio	t / h	Transport rate (Te) / mg · h ⁻¹	Recovery rate (Te) / % · h ⁻¹	Recovery yield / %
Bi ₂ Te ₃ /S	325	425	1:2	72	4.0	1.3	96.6
Bi ₂ Te ₃ /S	325	425	1:2	72	4.0	1.4	97.5
Bi ₂ Te ₃ /S	325	425	1:2	72	4.1	1.4	99.8
Bi ₂ Te ₃ /S	350	425	1:2	72	3.9	1.3	94.1
Bi ₂ Te ₃ /S	350	425	1:2	72	3.6	1.2	86.9
Bi ₂ Te ₃ /S	350	425	1:2	72	4.1	1.4	98.7
Bi ₂ Te ₃ /S	300	400	1:2	72	3.9	1.3	95.0
Bi ₂ Te ₃ /S	300	400	1:2	72	4.0	1.3	95.6
Bi ₂ Te ₃ /S	300	400	1:2	72	3.6	1.2	86.3
Bi ₂ Te ₃ /S	325	400	1:2	72	4.1	1.4	99.0
Bi ₂ Te ₃ /S	325	400	1:2	72	3.9	1.3	94.4
Bi ₂ Te ₃ /S	325	400	1:2	72	3.4	1.1	81.6
Bi ₂ Te ₃ /S	350	400	1:2	72	2.2	0.7	53.3
Bi ₂ Te ₃ /S	350	400	1:2	72	3.0	1.0	72.6
Bi ₂ Te ₃ /S	350	400	1:2	72	3.5	1.2	83.4
Bi ₂ Te ₃ /S	300	375	1:2	72	3.5	1.2	84.5
Bi ₂ Te ₃ /S	300	375	1:2	72	2.2	0.7	51.9
Bi ₂ Te ₃ /S	300	375	1:2	72	2.4	0.8	56.6
Bi ₂ Te ₃ /S	325	375	1:2	72	2.0	0.7	48.0
Bi ₂ Te ₃ /S	325	375	1:2	72	2.9	1.0	68.7
Bi ₂ Te ₃ /S	325	375	1:2	72	2.3	0.8	54.9
Bi ₂ Te ₃ /S	350	375	1:2	72	1.1	0.4	26.4
Bi ₂ Te ₃ /S	350	375	1:2	72	1.7	0.6	39.8
Bi ₂ Te ₃ /S	350	375	1:2	72	1.7	0.6	40.5

Table S2: Parameters and results of the closed Sb₂Te₃/S temperature gradient investigations.

System	T ₁ / °C	T ₂ / °C	Te:S molar ratio	t / h	Transport rate (Te) / mg · h ⁻¹	Recovery rate (Te) / % · h ⁻¹	Recovery yield / %
Sb ₂ Te ₃ /S	325	425	1:2	72	4.1	1.4	97.7
Sb ₂ Te ₃ /S	325	425	1:2	72	3.8	1.3	91.2
Sb ₂ Te ₃ /S	325	425	1:2	72	4.0	1.3	96.2
Sb ₂ Te ₃ /S	350	425	1:2	72	2.5	0.8	60.5
Sb ₂ Te ₃ /S	350	425	1:2	72	3.1	1.0	75.0
Sb ₂ Te ₃ /S	350	425	1:2	72	3.0	1.0	73.1
Sb ₂ Te ₃ /S	300	400	1:2	72	3.1	1.0	74.9
Sb ₂ Te ₃ /S	300	400	1:2	72	3.5	1.2	85.0
Sb ₂ Te ₃ /S	300	400	1:2	72	3.9	1.3	94.6
Sb ₂ Te ₃ /S	325	400	1:2	72	2.6	0.9	62.8
Sb ₂ Te ₃ /S	325	400	1:2	72	3.4	1.1	81.5
Sb ₂ Te ₃ /S	325	400	1:2	72	3.5	1.2	83.8
Sb ₂ Te ₃ /S	350	400	1:2	72	1.6	0.5	38.9
Sb ₂ Te ₃ /S	350	400	1:2	72	2.1	0.7	51.3
Sb ₂ Te ₃ /S	350	400	1:2	72	2.2	0.7	53.0
Sb ₂ Te ₃ /S	300	375	1:2	72	2.5	0.8	59.6
Sb ₂ Te ₃ /S	300	375	1:2	72	2.4	0.8	57.8
Sb ₂ Te ₃ /S	300	375	1:2	72	2.5	0.8	60.5
Sb ₂ Te ₃ /S	325	375	1:2	72	1.9	0.6	44.9
Sb ₂ Te ₃ /S	325	375	1:2	72	2.3	0.8	54.5
Sb ₂ Te ₃ /S	325	375	1:2	72	1.9	0.7	47.0
Sb ₂ Te ₃ /S	350	375	1:2	72	0.9	0.3	21.8
Sb ₂ Te ₃ /S	350	375	1:2	72	1.1	0.4	26.6
Sb ₂ Te ₃ /S	350	375	1:2	72	1.2	0.4	28.1

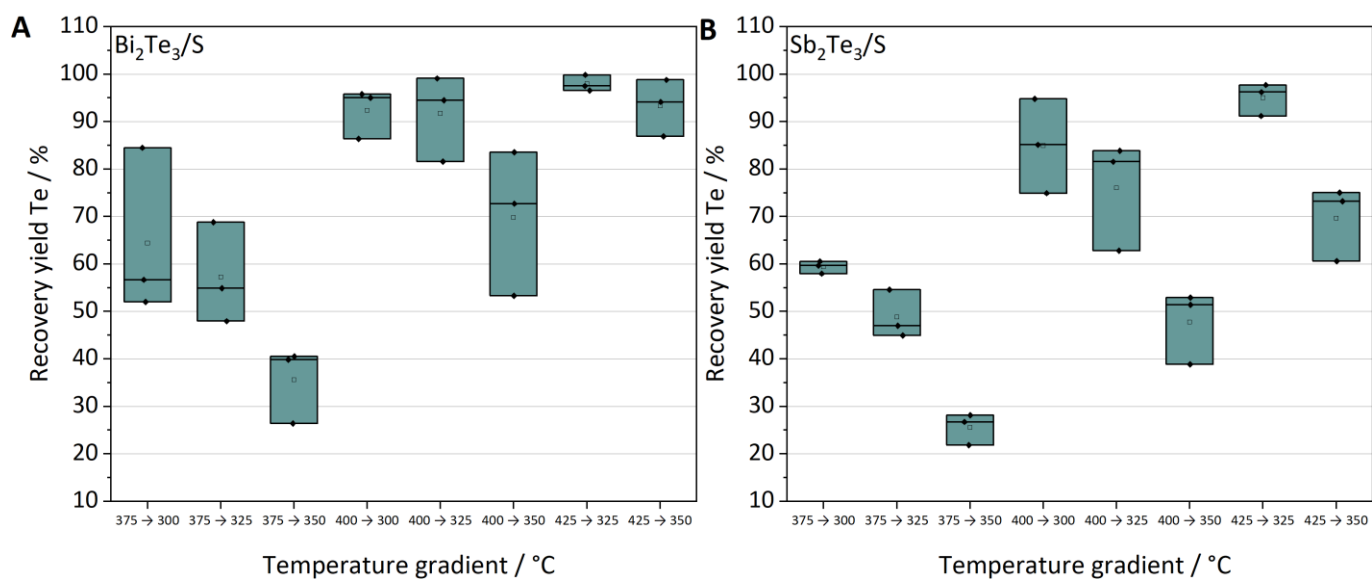


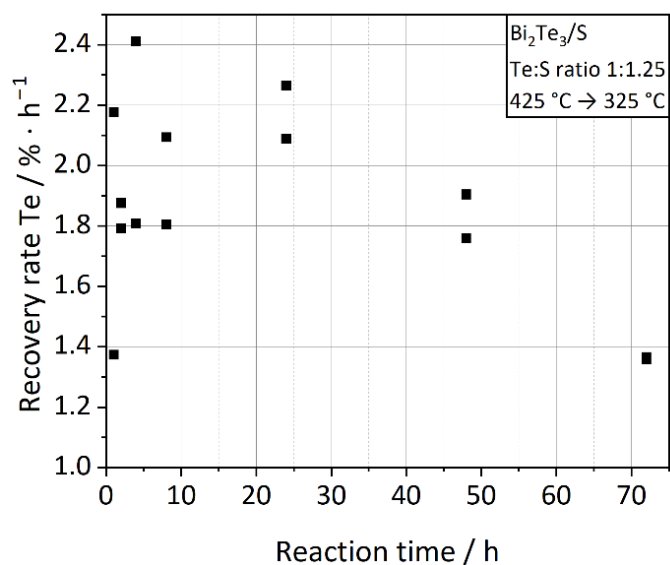
Figure S1: Box diagrams of recovery yields in closed experimental setups for both telluride systems (A: Bi₂Te₃/S, B: Sb₂Te₃/S). Eight different temperature gradients in the range of 300–425 °C were used. Furthermore, each black point represents one ampoule. This data was used to create the heat maps in Figure 3.

Table S3: Parameters and results of the closed Bi₂Te₃/S Te:S molar ratio and reaction time investigations.

System	T ₁ / °C	T ₂ / °C	Te:S molar ratio	t / h	Transport rate (Te) / mg · h ⁻¹	Recovery rate (Te) / % · h ⁻¹	Recovery yield / %
Bi ₂ Te ₃ /S	325	425	1:2	72	4.0	1.4	97.5
Bi ₂ Te ₃ /S	325	425	1:2	72	4.1	1.4	99.8
Bi ₂ Te ₃ /S	325	425	1:1.25	72	4.1	1.4	98.4
Bi ₂ Te ₃ /S	325	425	1:1.25	72	4.1	1.4	97.8
Bi ₂ Te ₃ /S	325	425	1:2	48	5.4	1.8	86.7
Bi ₂ Te ₃ /S	325	425	1:2	48	6.1	2.0	98.1
Bi ₂ Te ₃ /S	325	425	1:1.25	48	5.3	1.8	84.4
Bi ₂ Te ₃ /S	325	425	1:1.25	48	5.7	1.9	91.4
Bi ₂ Te ₃ /S	325	425	1:2	24	6.0	2.0	47.8
Bi ₂ Te ₃ /S	325	425	1:2	24	7.1	2.4	57.1
Bi ₂ Te ₃ /S	325	425	1:1.25	24	6.8	2.3	54.4
Bi ₂ Te ₃ /S	325	425	1:1.25	24	6.2	2.1	50.1
Bi ₂ Te ₃ /S	325	375	1:2	72	1.9	0.6	45.4
Bi ₂ Te ₃ /S	325	375	1:2	72	2.7	0.9	65.6
Bi ₂ Te ₃ /S	325	375	1:1.25	72	2.1	0.7	50.7
Bi ₂ Te ₃ /S	325	375	1:1.25	72	2.9	1.0	69.6
Bi ₂ Te ₃ /S	325	375	1:2	48	2.6	0.9	41.8
Bi ₂ Te ₃ /S	325	375	1:2	48	2.8	0.9	44.7
Bi ₂ Te ₃ /S	325	375	1:1.25	48	2.7	0.9	43.6
Bi ₂ Te ₃ /S	325	375	1:1.25	48	2.7	0.9	43.6
Bi ₂ Te ₃ /S	325	375	1:2	24	2.9	1.0	23.1
Bi ₂ Te ₃ /S	325	375	1:2	24	2.8	0.9	22.2
Bi ₂ Te ₃ /S	325	375	1:1.25	24	2.2	0.7	17.4
Bi ₂ Te ₃ /S	325	375	1:1.25	24	2.6	0.9	20.9

Table S4: Parameters and results of the closed $\text{Bi}_2\text{Te}_3/\text{S}$ recovery rate investigations.

System	$T_1 / ^\circ\text{C}$	$T_2 / ^\circ\text{C}$	Te:S molar ratio	t / h	Transport rate (Te) / $\text{mg} \cdot \text{h}^{-1}$	Recovery rate (Te) / $\% \cdot \text{h}^{-1}$	Recovery yield / $\%$
$\text{Bi}_2\text{Te}_3/\text{S}$	325	425	1:1.25	1	4.1	1.4	1.4
$\text{Bi}_2\text{Te}_3/\text{S}$	325	425	1:1.25	1	6.5	2.2	2.2
$\text{Bi}_2\text{Te}_3/\text{S}$	325	425	1:1.25	2	5.6	1.9	3.8
$\text{Bi}_2\text{Te}_3/\text{S}$	325	425	1:1.25	2	5.4	1.8	3.6
$\text{Bi}_2\text{Te}_3/\text{S}$	325	425	1:1.25	4	7.2	2.4	9.6
$\text{Bi}_2\text{Te}_3/\text{S}$	325	425	1:1.25	4	5.4	1.8	7.3
$\text{Bi}_2\text{Te}_3/\text{S}$	325	425	1:1.25	8	5.4	1.8	14.4
$\text{Bi}_2\text{Te}_3/\text{S}$	325	425	1:1.25	8	6.9	2.3	18.4
$\text{Bi}_2\text{Te}_3/\text{S}$	325	425	1:1.25	24	6.2	2.1	50.1
$\text{Bi}_2\text{Te}_3/\text{S}$	325	425	1:1.25	24	6.8	2.3	54.4
$\text{Bi}_2\text{Te}_3/\text{S}$	325	425	1:1.25	48	5.3	1.8	84.4
$\text{Bi}_2\text{Te}_3/\text{S}$	325	425	1:1.25	48	5.7	1.9	91.4
$\text{Bi}_2\text{Te}_3/\text{S}$	325	375	1:1.25	72	4.1	1.4	98.4
$\text{Bi}_2\text{Te}_3/\text{S}$	325	375	1:1.25	72	4.1	1.4	97.8

Figure S2: Recovery rates in closed experimental setups in dependence on different reaction times (1 h, 2 h, 4 h, 8 h, 24 h, 48 h, 72 h) for the system $\text{Bi}_2\text{Te}_3/\text{S}$ with a Te:S ratio of 1:1.25 at a temperature gradient of 425 °C → 325 °C.

Differential scanning calorimetry (DSC)

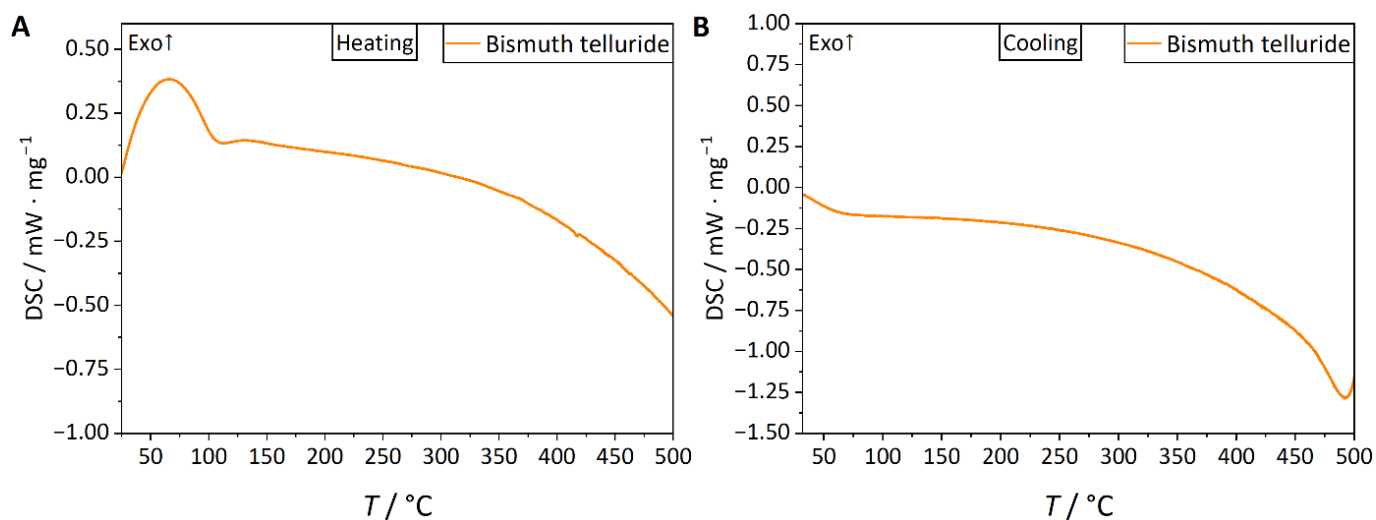


Figure S3: Heat flow determined by DSC (A: Heating and B: Cooling) of a bismuth telluride reference sample.

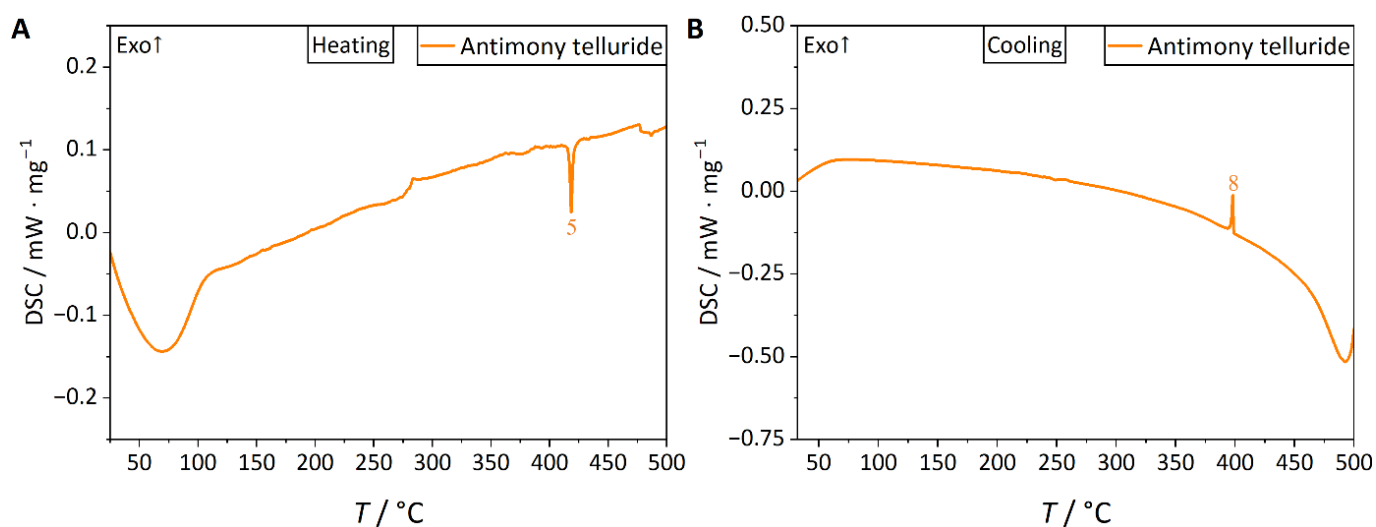


Figure S4: Heat flow determined by DSC (A: Heating and B: Cooling) of an antimony telluride reference sample. Additionally, eutectic temperature of antimony and tellurium (5) and crystallisation (8) of this melt is marked as in Figure 3 in the main article.

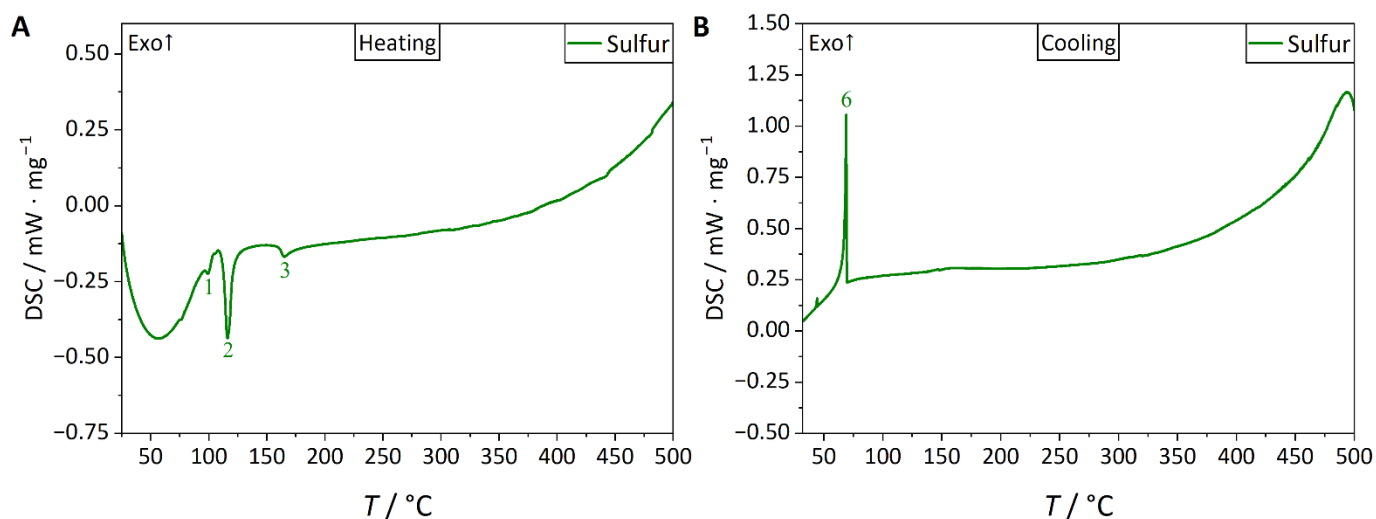


Figure S5: Heat flow determined by DSC (A: Heating and B: Cooling) of a sulfur reference sample. Additionally, transition of orthorhombic α -sulfur to monoclinic β -sulfur (1), melting (2), polymerization (3) and crystallisation (6) of sulfur is marked as in Figure 3 in the main article.

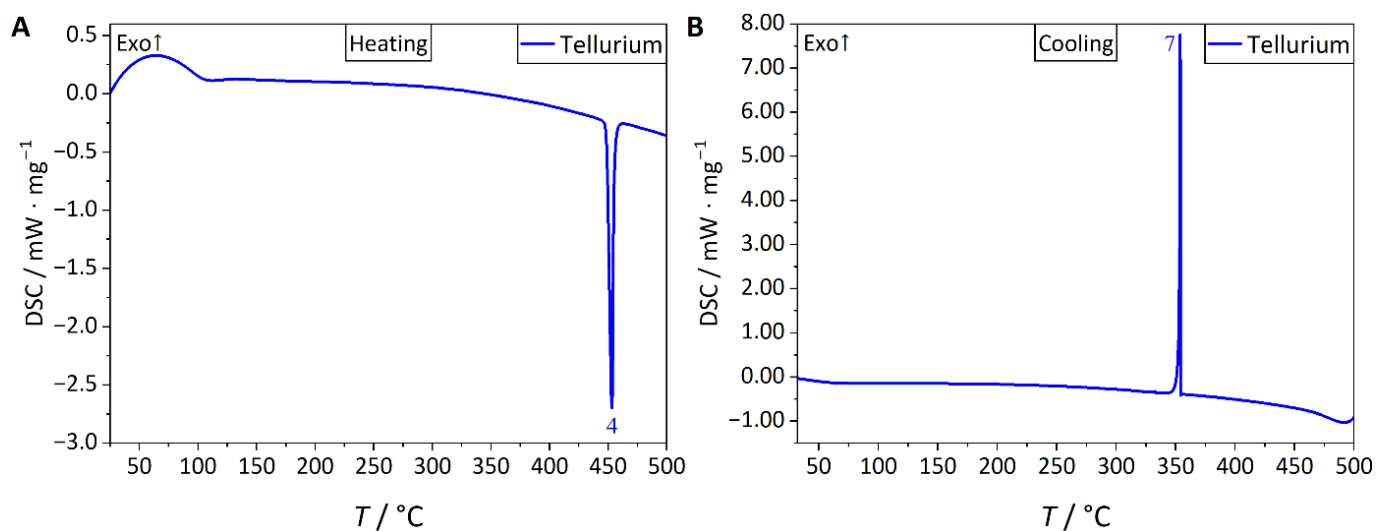


Figure S6: Heat flow determined by DSC (A: Heating and B: Cooling) of a tellurium reference sample. Additionally, melting (4) and crystallisation (7) of tellurium is marked as in Figure 3 in the main article.

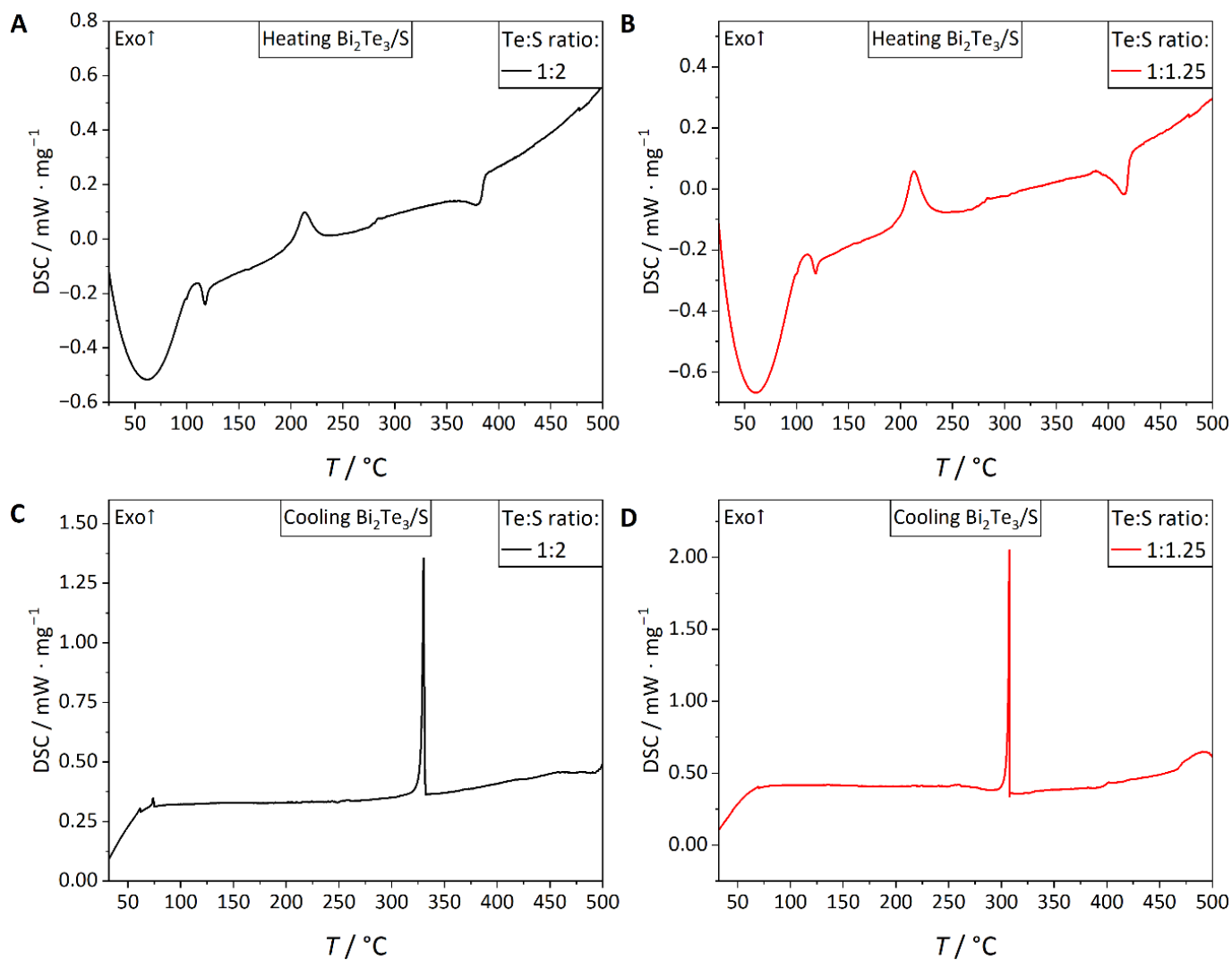


Figure S7: Heat flow determined by DSC (A&B: Heating, C&D: Cooling) of bismuth telluride and sulfur mixtures with two different Te:S molar ratios (Black: 1:2, Red: 1:1.25).

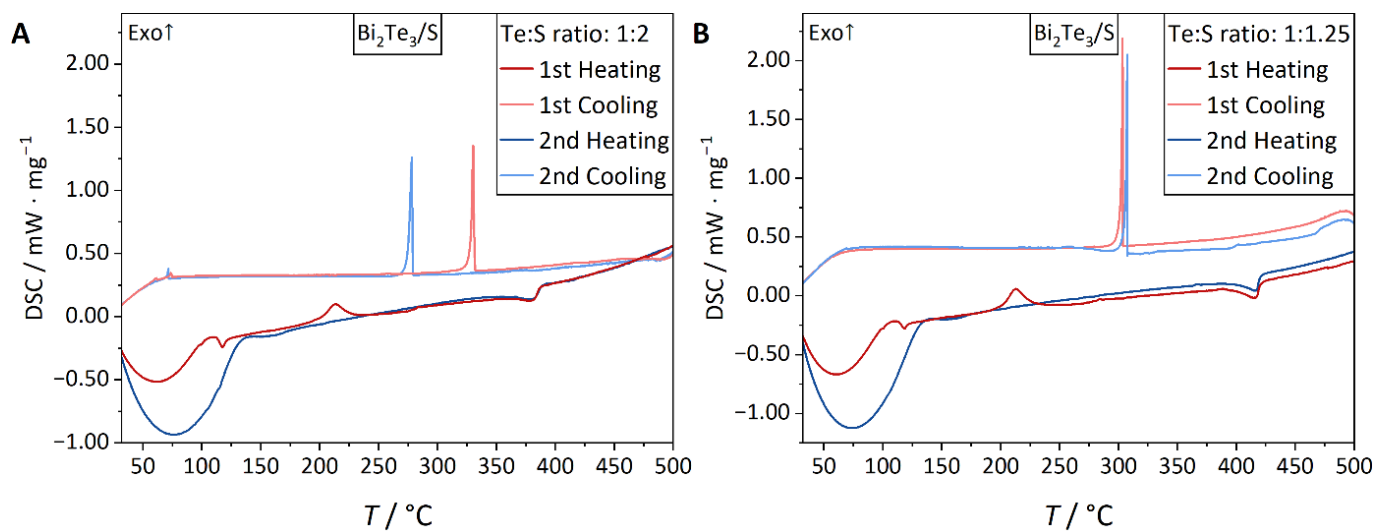


Figure S8: Two DSC-cycles (red: First cycle, blue: Second cycle) of bismuth telluride and sulfur mixtures with two different Te:S molar ratios (A:1:2, B: 1:1.25).

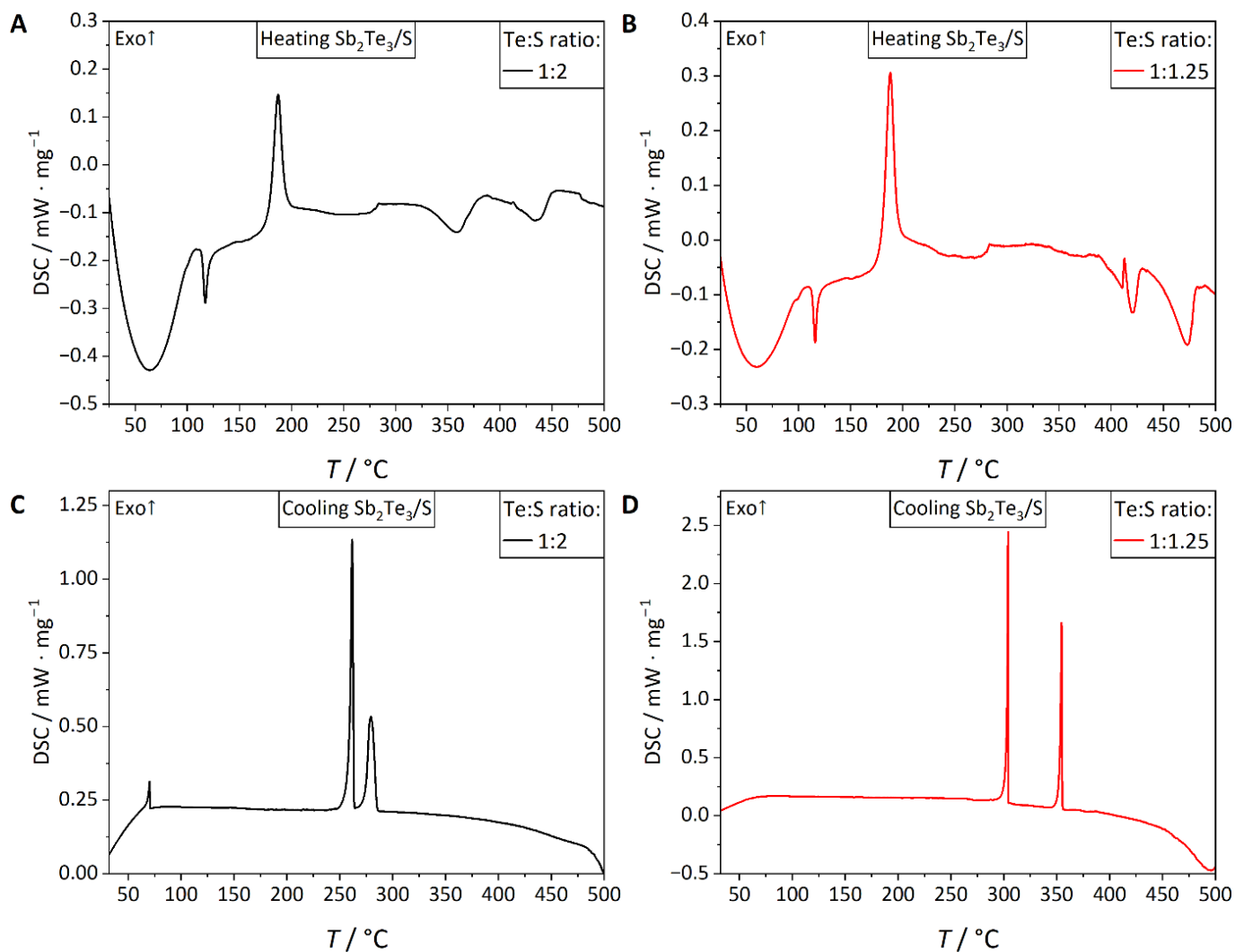


Figure S9: Heat flow determined by DSC (A&B: Heating, C&D: Cooling) of antimony telluride and sulfur mixtures with two different Te:S molar ratios (Black: 1:2, Red: 1:1.25).

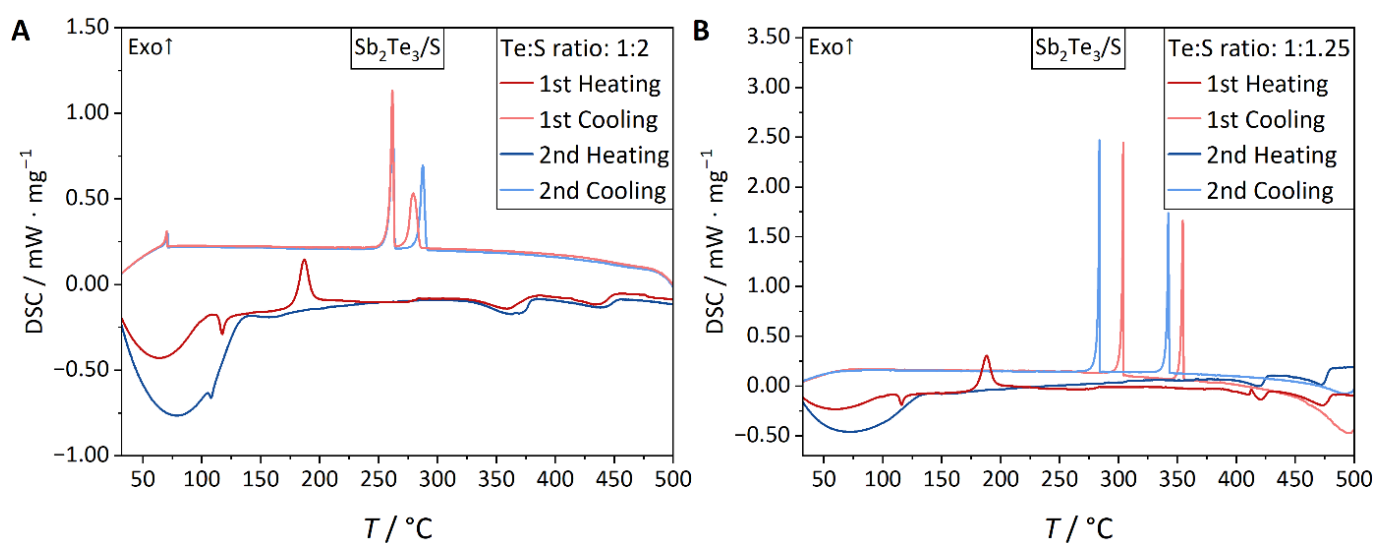


Figure S10: Two DSC-cycles (red: First cycle, blue: Second cycle) of antimony telluride and sulfur mixtures with two different Te:S molar ratios (A:1:2, B: 1:1.25).

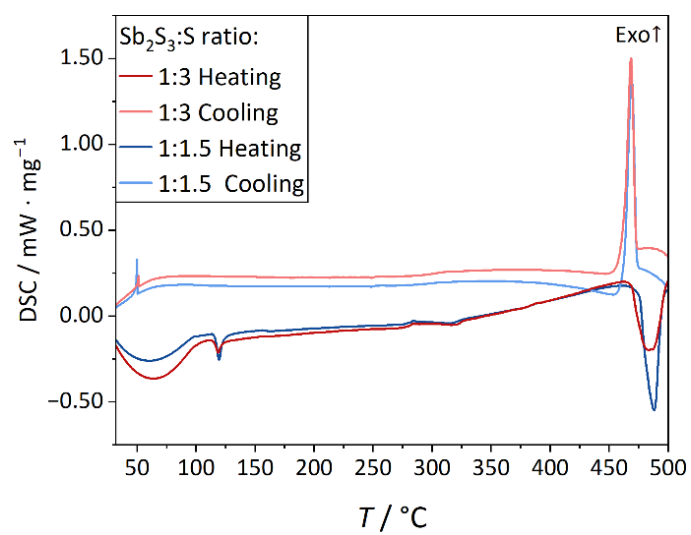


Figure S11: DSC-cycles of antimony sulfide and sulfur mixtures with two different Sb₂S₃:S molar ratios (red: 1:1, blue: 1:0.25).

Powder X-ray diffractometry (PXRD)

In all shown PXRDs of the source, lower tellurium recovery rates are the reason why tellurium reflections are still observable.

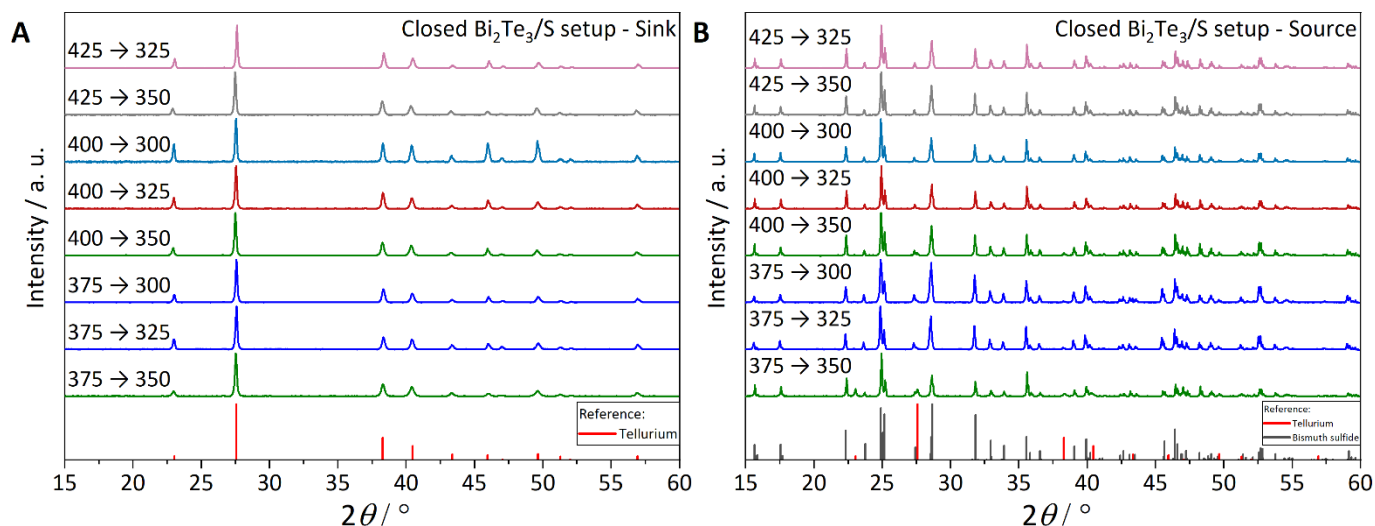


Figure S12: One exemplary PXRD-data for each closed experimental $\text{Bi}_2\text{Te}_3/\text{S}$ setup (A: Sink and B: Source) with varying temperature gradient. Additionally, reference patterns are shown for tellurium¹ and bismuth sulfide².

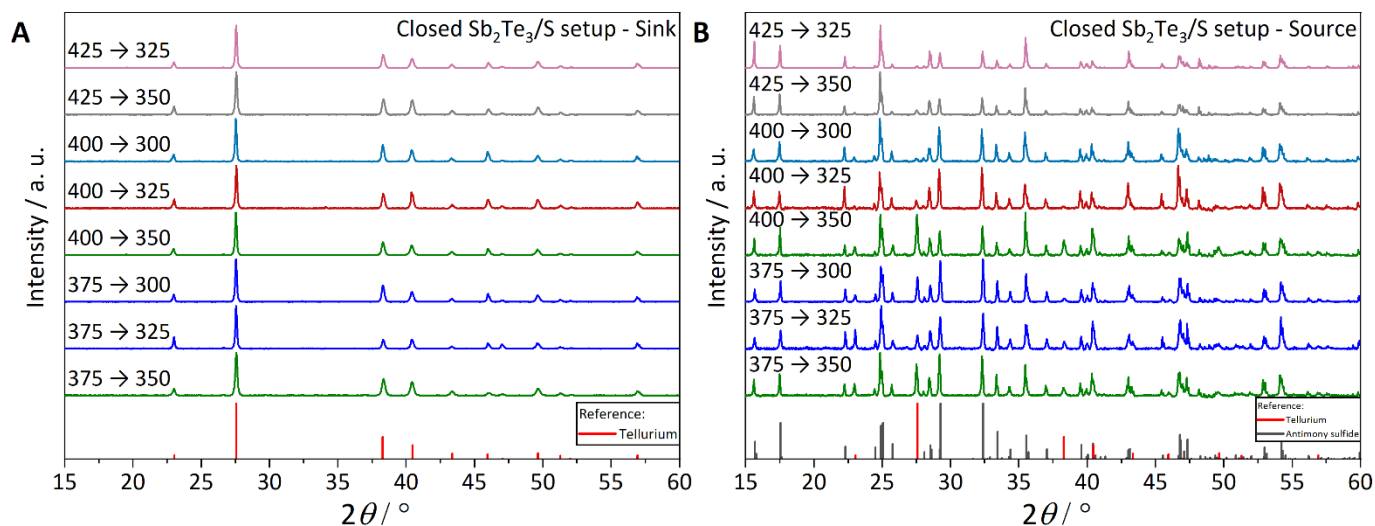


Figure S13: One exemplary PXRD-data for each closed experimental $\text{Sb}_2\text{Te}_3/\text{S}$ setup (A: Sink and B: Source) with varying temperature gradient. Additionally, reference patterns are shown for tellurium¹ and antimony sulfide³.

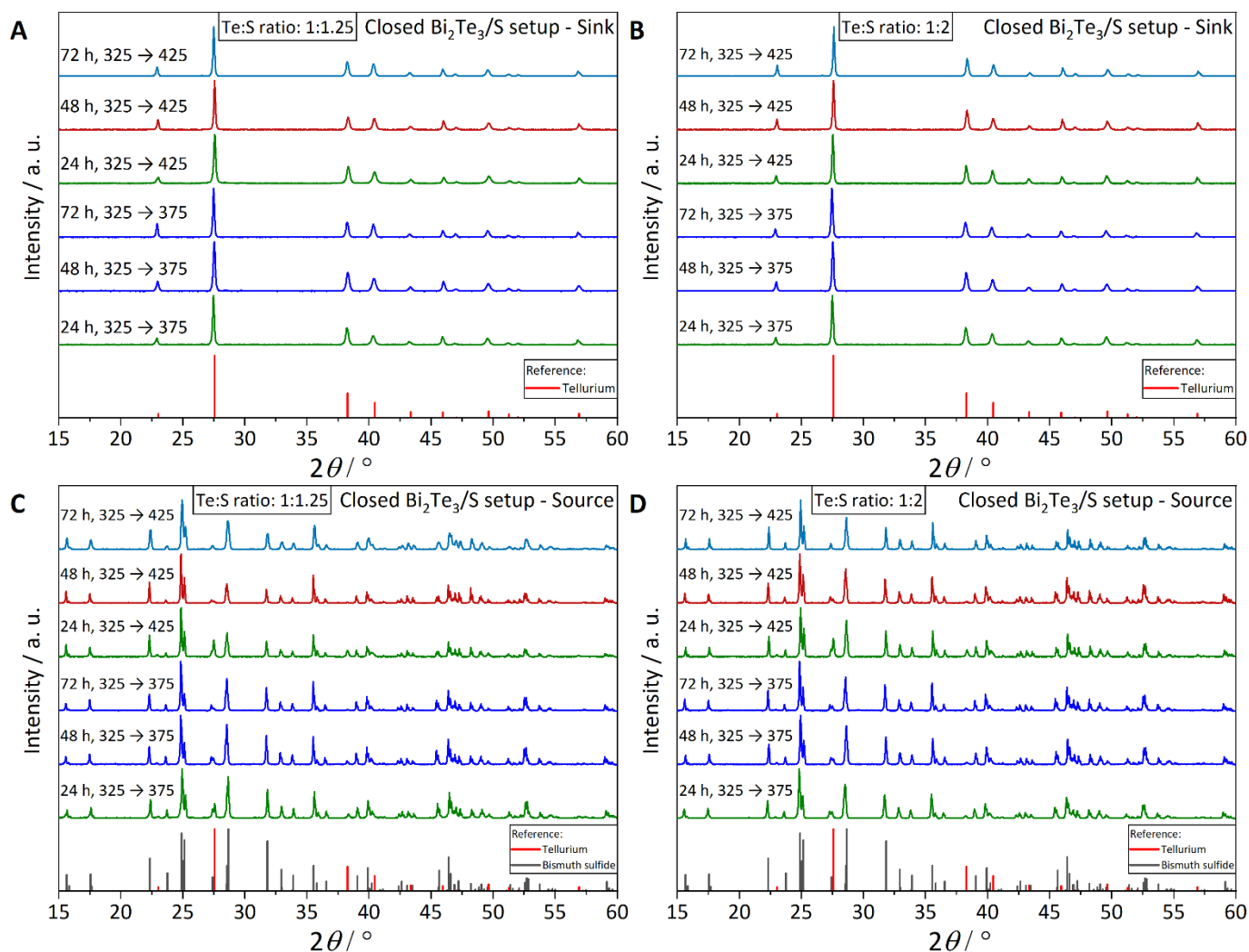


Figure S14: One exemplary PXRD-data for each closed experimental $\text{Bi}_2\text{Te}_3/\text{S}$ setup (A, B: Sink and C, D: Source) with varying Te:S molar ratio (A, C: 1:1.25 or B, D: 1:2) at different temperature gradients (325 $\rightarrow$ 425 or 325 $\rightarrow$ 375) and reaction times (24 h, 48 h, 72 h). Additionally, reference patterns are shown for tellurium¹ and bismuth sulfide².

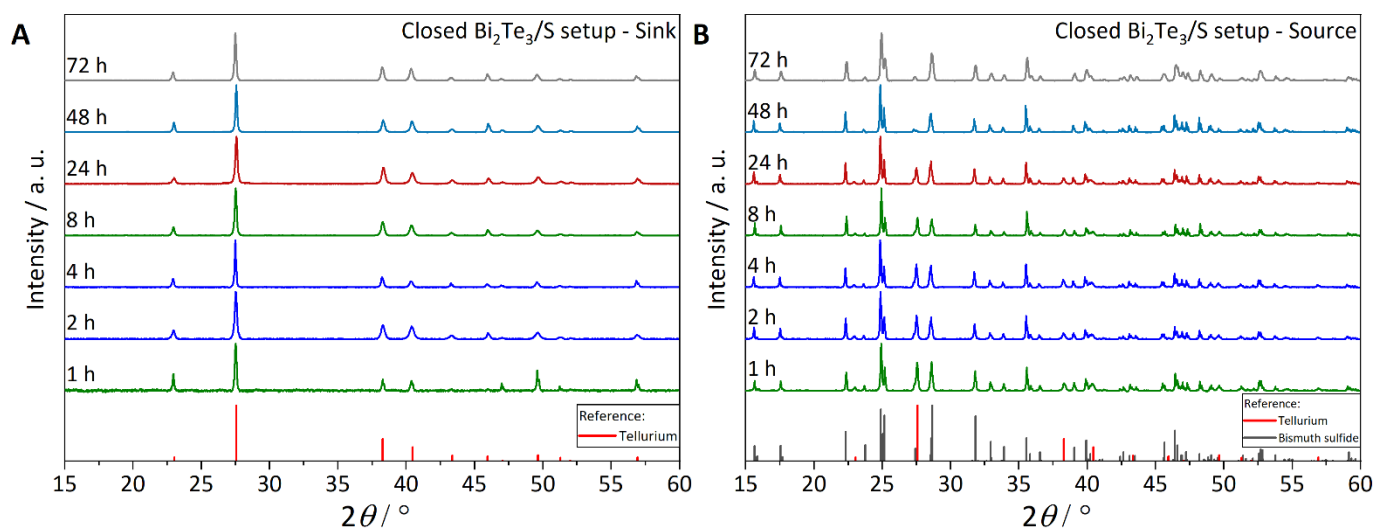


Figure S15: One exemplary PXRD-data for each closed experimental $\text{Bi}_2\text{Te}_3/\text{S}$ setup (A: Sink and B: Source) with varying reaction time (1 h, 2 h, 4 h, 8 h, 24 h, 48 h, 72 h). Additionally, reference patterns are shown for tellurium¹ and bismuth sulfide².

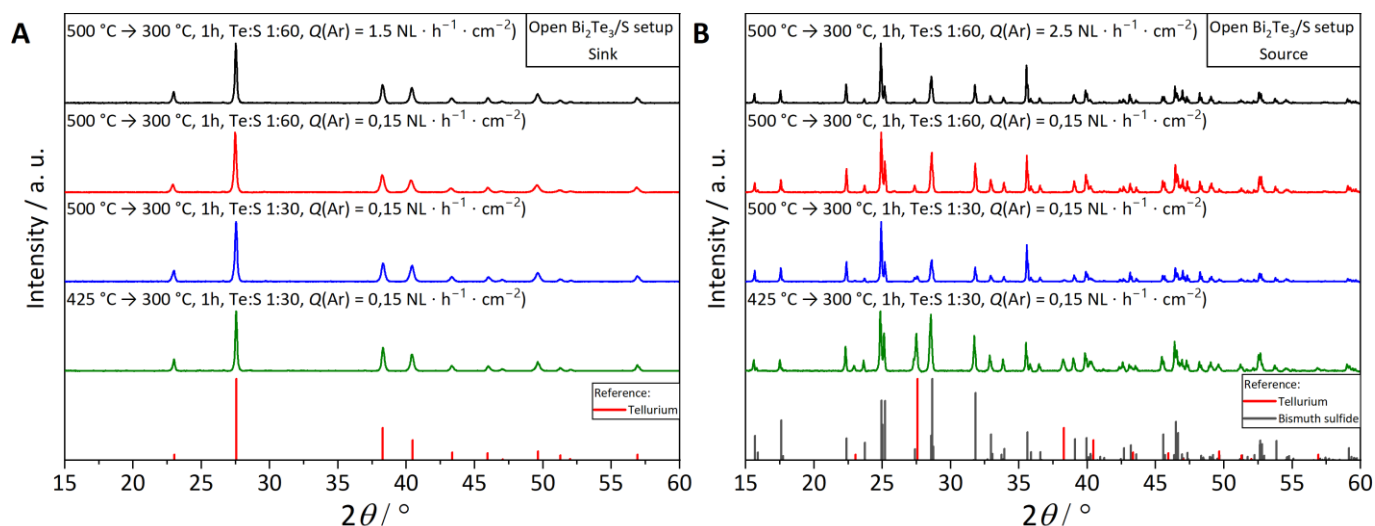


Figure S16: PXRD-data of four different open experimental setups (A: Sink and B: Source) for the $\text{Bi}_2\text{Te}_3/\text{S}$ system. Additionally, reference patterns are shown for tellurium¹ and bismuth sulfide².

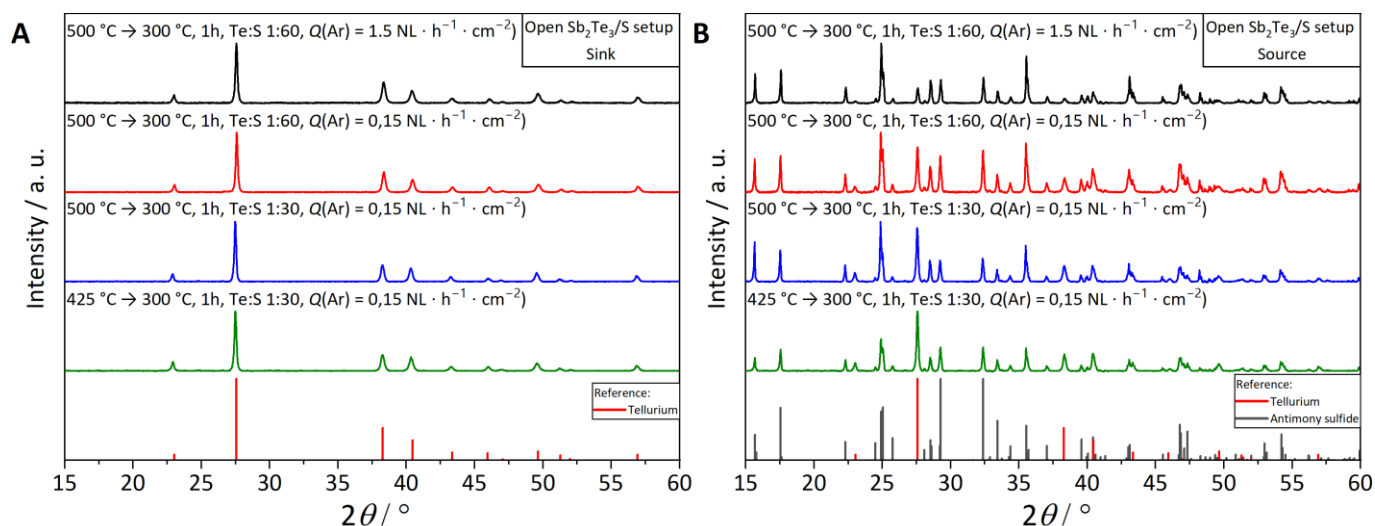


Figure S17: PXRD-data of four different open experimental setups (A: Sink and B: Source) for the $\text{Sb}_2\text{Te}_3/\text{S}$ system. Additionally, reference patterns are shown for tellurium¹ and antimony sulfide³.

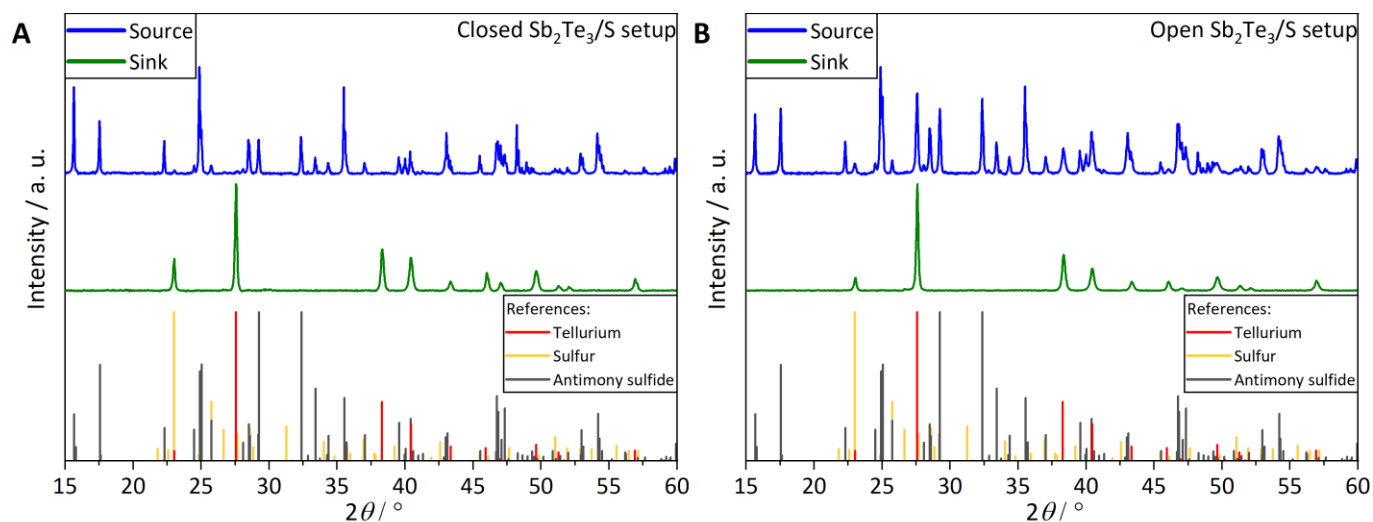


Figure S18: PXRD-data of source (blue diffractogram) and sink (green diffractogram) products of (A) best closed and (B) best open experimental $\text{Sb}_2\text{Te}_3/\text{S}$ setup. Additionally, references for tellurium¹, sulfur⁴ and antimony sulfide³ are shown.

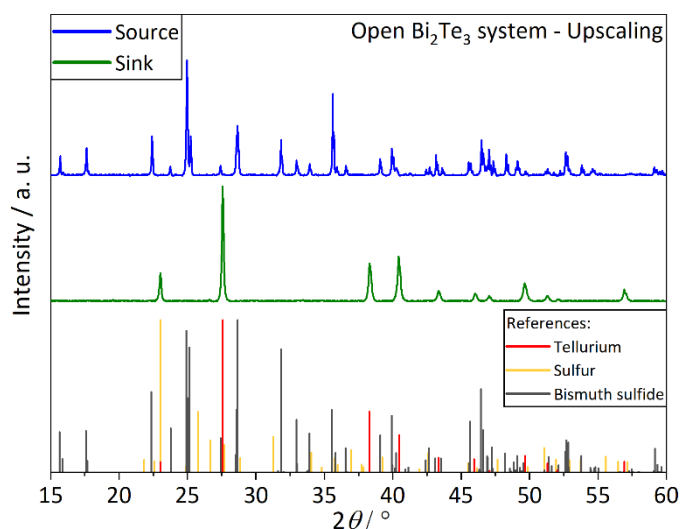


Figure S19: PXRD-data of source (blue diffractogram) and sink (green diffractogram) products of upscaling of open experimental $\text{Bi}_2\text{Te}_3/\text{S}$ setup. Additionally, references for tellurium¹, sulfur⁴ and bismuth sulfide² are shown.

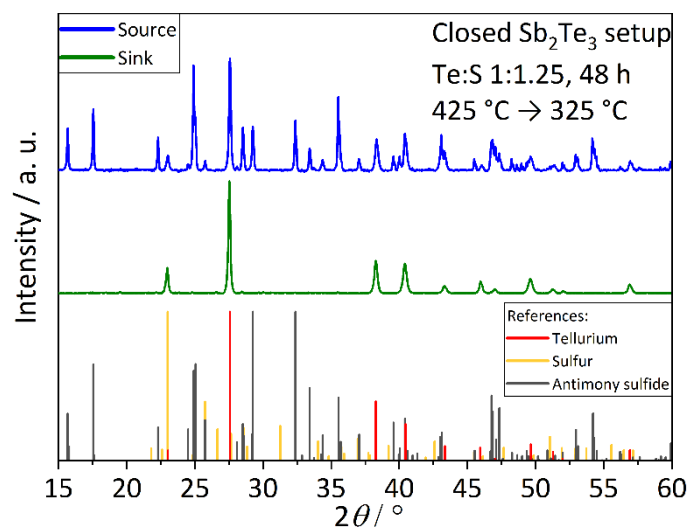


Figure S20: PXRD-data of source (blue diffractogram) and sink (green diffractogram) products of the $\text{Sb}_2\text{Te}_3/\text{S}$ experimental setup with a reaction of 48 h and a Te:S molar ratio of 1:1.25 at a temperature gradient of 425 °C $\rightarrow$ 325 °C. Additionally, references for tellurium¹, sulfur⁴ and antimony sulfide³ are shown.

Raman spectroscopy

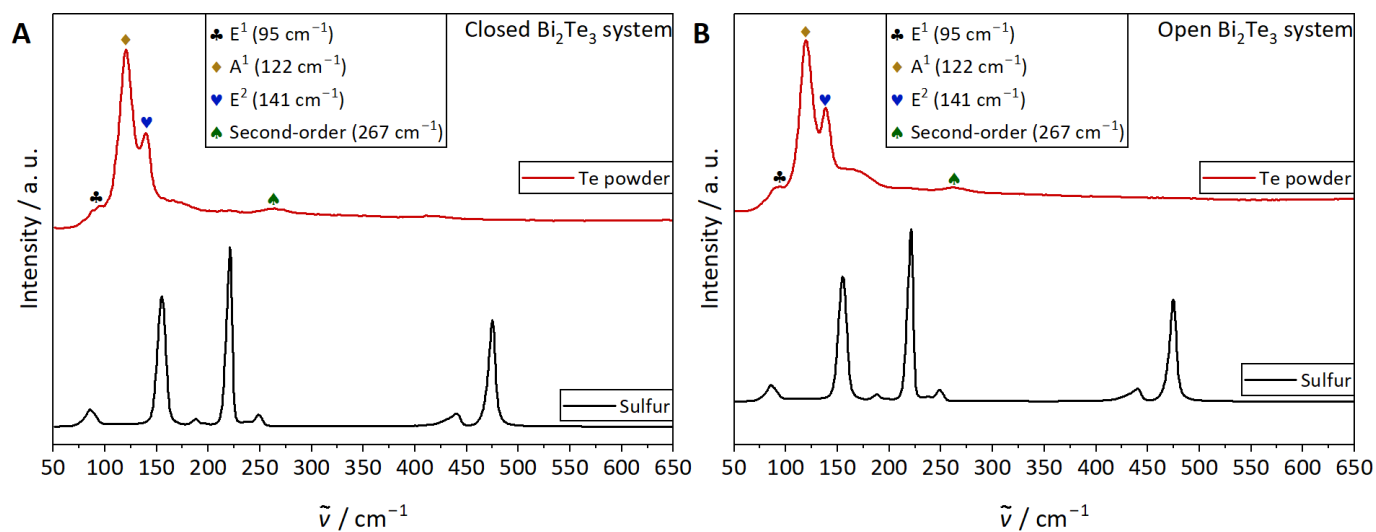


Figure S21: Raman spectra for tellurium recovered in (A) best closed and (B) best open experimental $\text{Bi}_2\text{Te}_3/\text{S}$ setup. A reference measurement of sulfur is also shown, and the specific Raman modes of tellurium are marked.

Energy dispersive X-ray analysis (EDX)

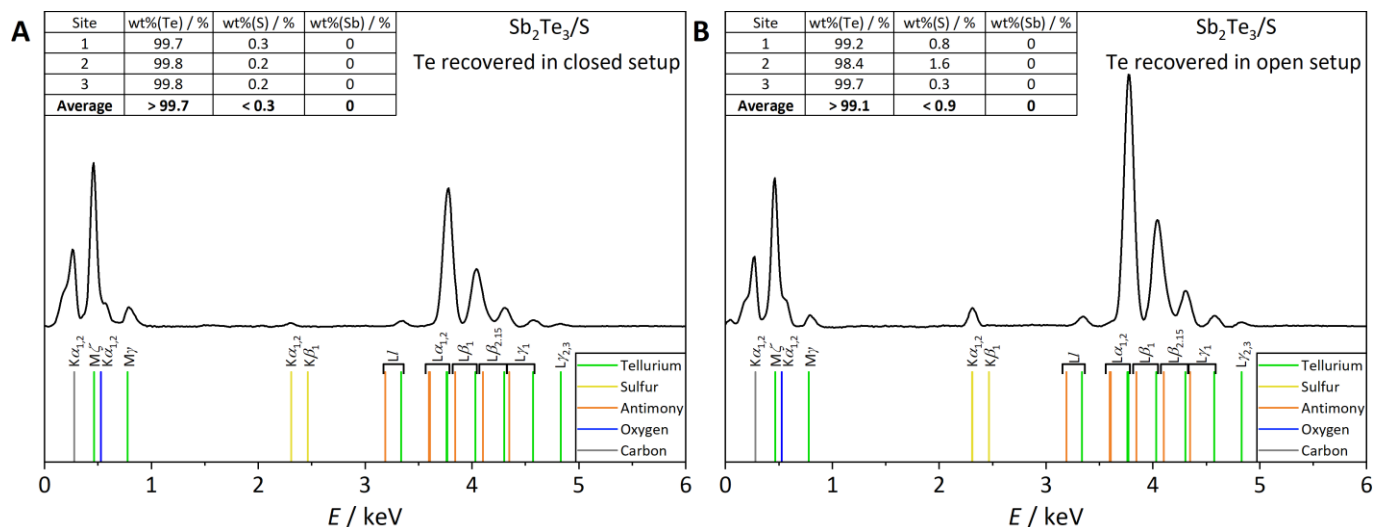


Figure S22: EDX-data of tellurium recovered in (A) the best-performing closed Sb₂Te₃/S experimental setup and (B) the best-performing open Sb₂Te₃/S experimental setup. For each sample, an average wt% value is given. It is calculated from three different measuring spots. X-ray emission lines are also shown for tellurium, sulfur, antimony, oxygen, and carbon as references.⁵

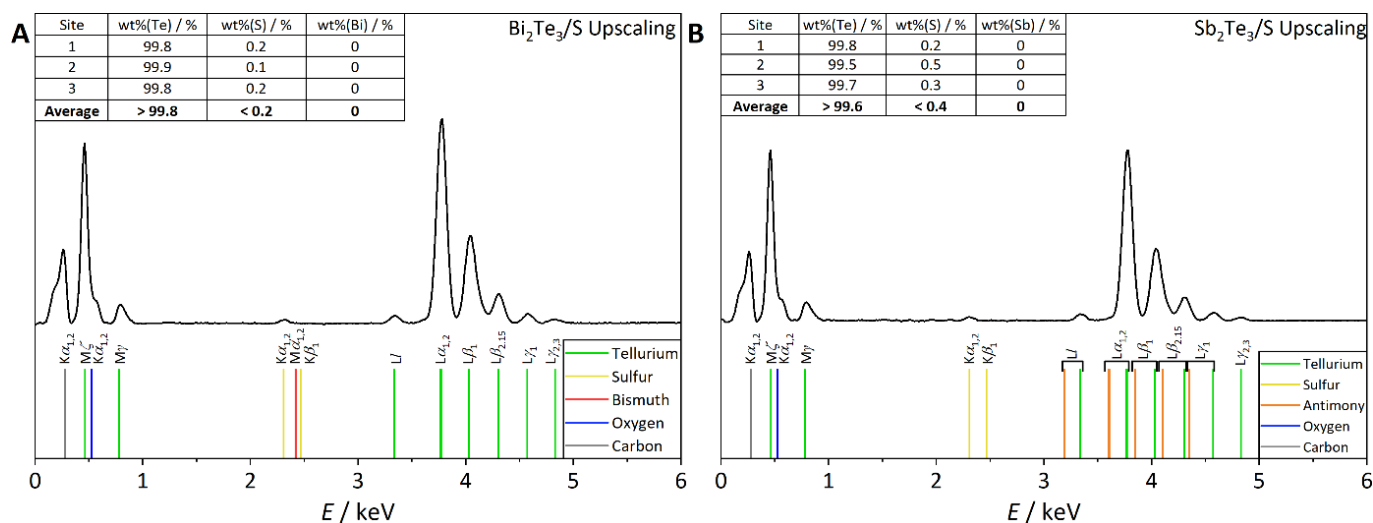


Figure S23: EDX-data of tellurium recovered in (A) the open Bi₂Te₃/S upscaling setup and (B) the open Sb₂Te₃/S upscaling setup. For each sample, an average wt% value is given. It is calculated from three different measuring spots. X-ray emission lines are also shown for tellurium, sulfur, bismuth, antimony, oxygen, and carbon as references.⁵

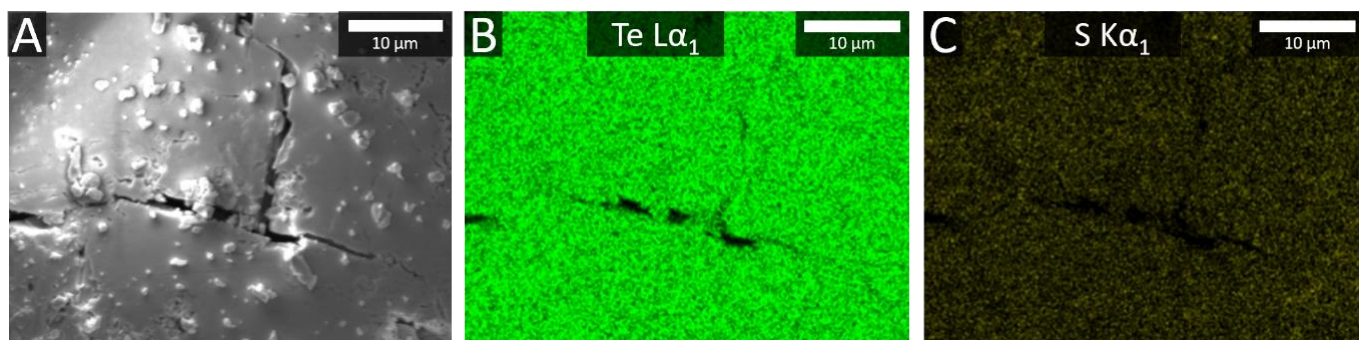


Figure S24: Elemental Mapping of a tellurium sample recovered in the best-performing open $\text{Bi}_2\text{Te}_3/\text{S}$ experimental setup. Image (A) shows the electron image, image (B) shows the elemental mapping of the tellurium $\text{L}\alpha_1$ X-ray emission line and image (C) shows the elemental mapping of the sulfur $\text{K}\alpha_1$ X-ray emission line.

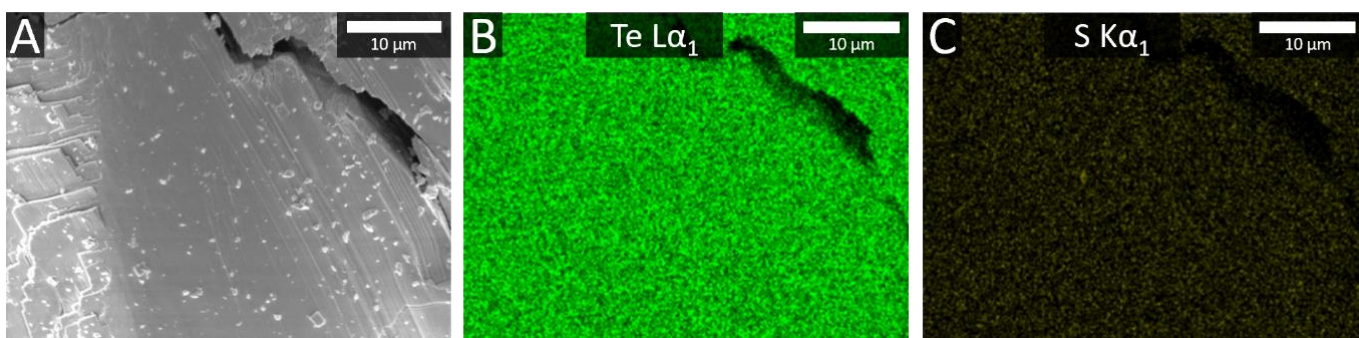


Figure S25: Elemental Mapping of a tellurium sample recovered in the best-performing closed $\text{Sb}_2\text{Te}_3/\text{S}$ experimental setup. Image (A) shows the electron image, image (B) shows the elemental mapping of the tellurium $\text{L}\alpha_1$ X-ray emission line and image (C) shows the elemental mapping of the sulfur $\text{K}\alpha_1$ X-ray emission line.

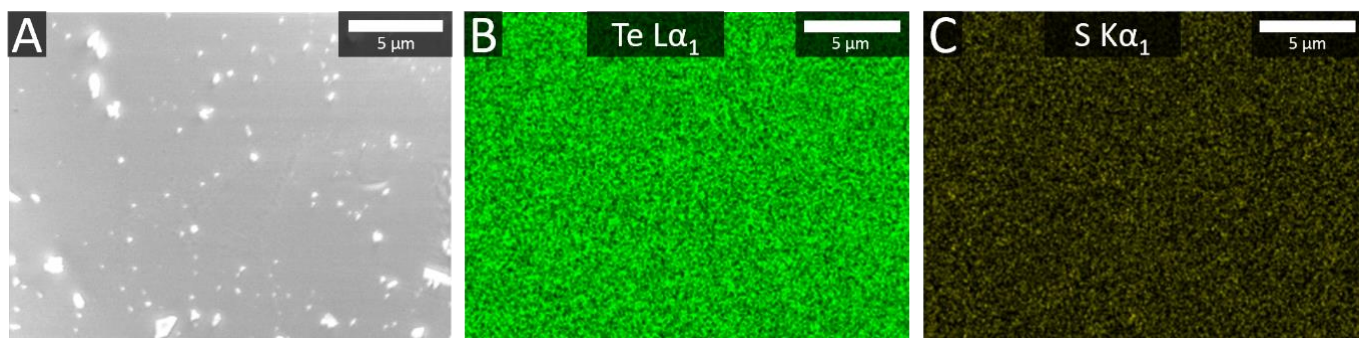


Figure S26: Elemental Mapping of a tellurium sample recovered in the best-performing open $\text{Sb}_2\text{Te}_3/\text{S}$ experimental setup. Image (A) shows the electron image, image (B) shows the elemental mapping of the tellurium $\text{L}\alpha_1$ X-ray emission line and image (C) shows the elemental mapping of the sulfur $\text{K}\alpha_1$ X-ray emission line.

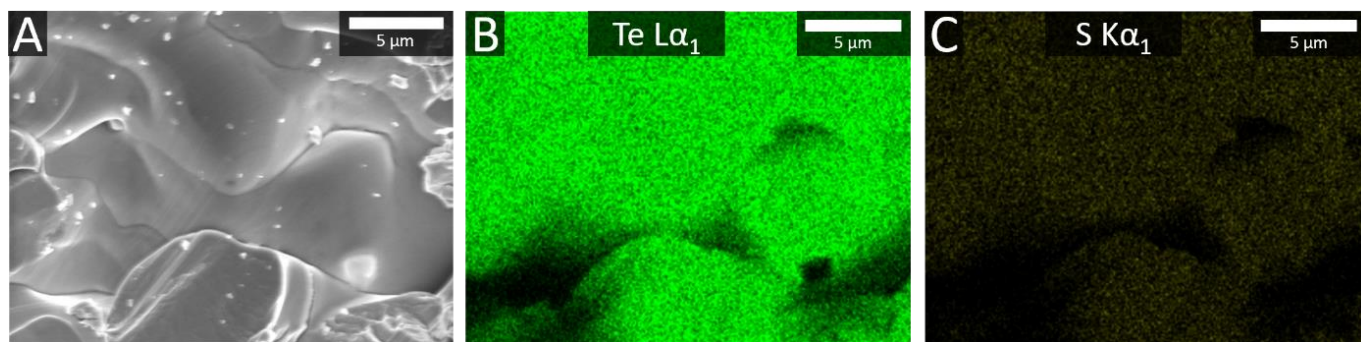


Figure S27: Elemental Mapping of a tellurium sample recovered in the open $\text{Bi}_2\text{Te}_3/\text{S}$ upscaling setup. Image (A) shows the electron image, image (B) shows the elemental mapping of the tellurium $\text{L}\alpha_1$ X-ray emission line and image (C) shows the elemental mapping of the sulfur $\text{K}\alpha_1$ X-ray emission line.

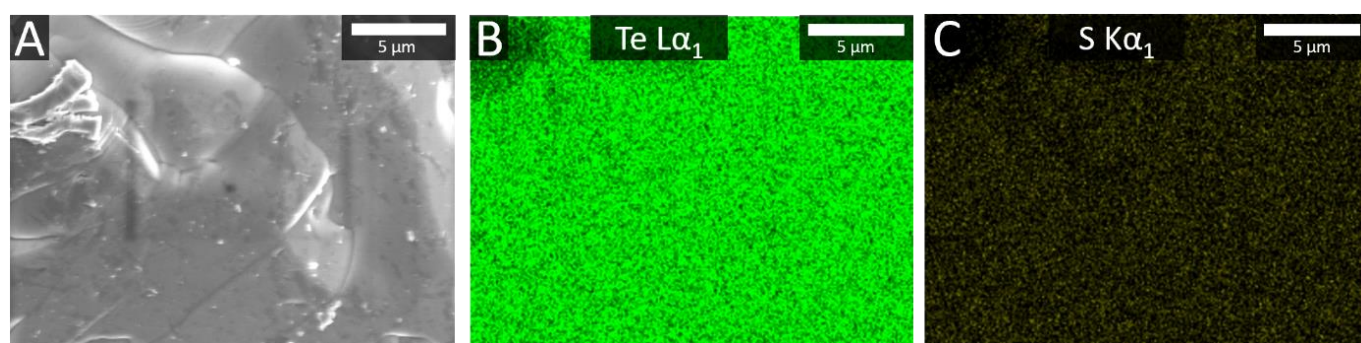


Figure S28: Elemental Mapping of a tellurium sample recovered in the open $\text{Sb}_2\text{Te}_3/\text{S}$ upscaling setup. Image (A) shows the electron image, image (B) shows the elemental mapping of the tellurium $\text{L}\alpha_1$ X-ray emission line and image (C) shows the elemental mapping of the sulfur $\text{K}\alpha_1$ X-ray emission line.

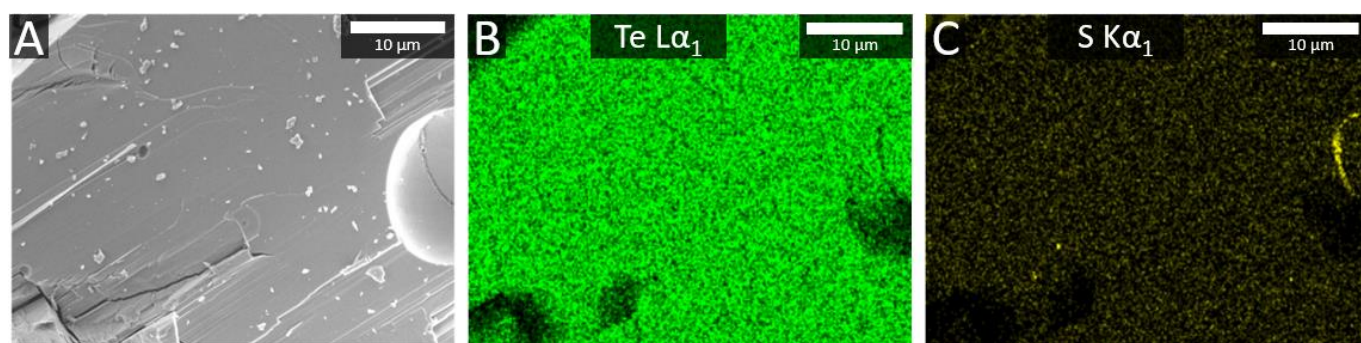


Figure S29: Elemental Mapping of a tellurium sample after a purification step at $425\text{ }^\circ\text{C}$. Image (A) shows the electron image, image (B) shows the elemental mapping of the tellurium $\text{L}\alpha_1$ X-ray emission line and image (C) shows the elemental mapping of the sulfur $\text{K}\alpha_1$ X-ray emission line.

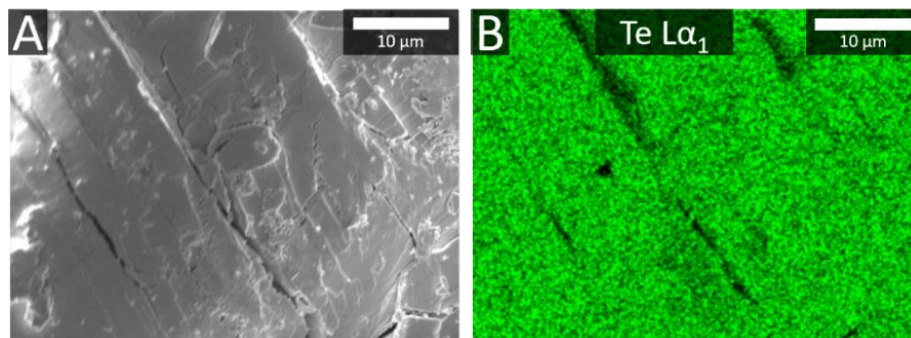


Figure S30: Elemental Mapping of a tellurium sample after a purification step at 500 °C. Image (A) shows the electron image, and image (B) shows the elemental mapping of the tellurium $L\alpha_1$ X-ray emission line.

References

- 1 C. Adenis, V. Langer and O. Lindqvist, *Acta Crystallographica Section C*, 1989, **45**, 941–942.
- 2 A. Kyono and M. Kimata, *American Mineralogist*, 2004, **89**, 932–940.
- 3 W. Hofmann, *Zeitschrift für Kristallographie - Crystalline materials*, 1933, **86**, 225–245.
- 4 B. E. Warren and J. T. Burwell, *The Journal of Chemical Physics*, 1935, **3**, 6–8.
- 5 J. A. Bearden, *Rev. Mod. Phys.*, 1967, **39**, 78–124.